

SWITCHMODE Power Rectifier

MUR210

SWITCHMODE power rectifiers are state-of-the-art devices that are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 20 Nanosecond Recovery Times
- 175 °C Operating Junction Temperature
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- These are Pb-Free Devices*

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 0.4 Gram (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 220 °C Max for 10 Seconds, 1/16" from Case
- Polarity: Cathode Indicated by Polarity Band

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100 -	V
Average Rectified Forward Current (Square Wave Mounting Method #3) (Note 2)	I _{F(AV)}	2.0 @ T _A = 100 °C	Α
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	35	A
Operating Junction Temperature and Storage Temperature Range	T _J , T _{stg}	-65 to +175	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	See Note 4	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.
- * For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ULTRAFAST RECTIFIERS2 AMPERES, 100 VOLTS





MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MUR210RLG	Axial Lead*	5000/Tape & Reel

DISCONTINUED (Note 1)

MUR210	Axial Lead*	1000 Units/Bag
MUR210G	Axial Lead*	1000 Units/Bag
MUR210RL	Axial Lead*	5000/Tape & Reel

- † For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.
- * This package is inherently Pb-Free.
- DISCONTINUED: These devices are not recommended for new design. Please contact your onsemi representative for information. The most current information on these devices may be available on www.onsemi.com.

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ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 3) $ (I_F = 2.0 \text{ A, } T_J = 150 ^{\circ}\text{C}) $ $ (I_F = 2.0 \text{ A, } T_J = 25 ^{\circ}\text{C}) $	V _F	0.74 0.94	V
Maximum Instantaneous Reverse Current (Note 3) (Rated DC Voltage, $T_J = 150 ^{\circ}\text{C}$) (Rated DC Voltage, $T_J = 25 ^{\circ}\text{C}$)	i _R	50 2.0	μΑ
Maximum Reverse Recovery Time $ \begin{aligned} (I_F = 1.0 \text{ A, di/dt} = 50 \text{ A/}\mu\text{s}) \\ (I_F = 0.5 \text{ A, } I_R = 1.0 \text{ A, } I_{REC} = 0.25 \text{ A}) \end{aligned} $	t _{rr}	30 20	ns
Maximum Forward Recovery Time (I _F = 1.0 A, di/dt = 100 A/ μ s, I _{REC} to 1.0 V)	t _{fr}	20	ns

^{3.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

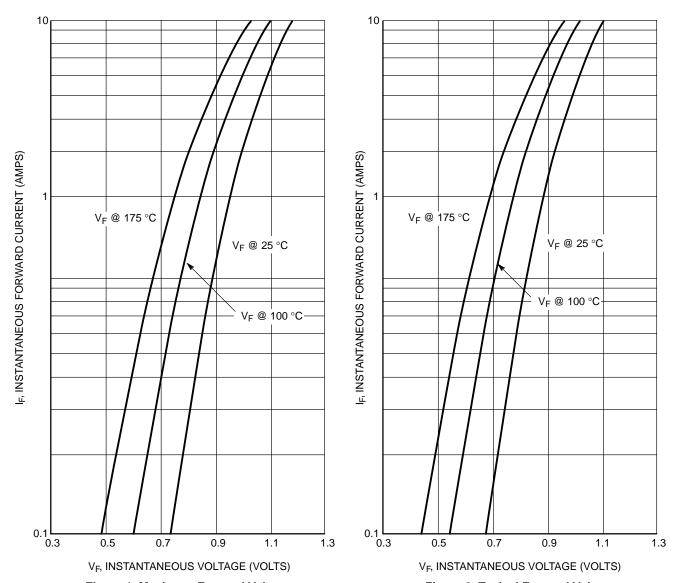


Figure 1. Maximum Forward Voltage

Figure 2. Typical Forward Voltage

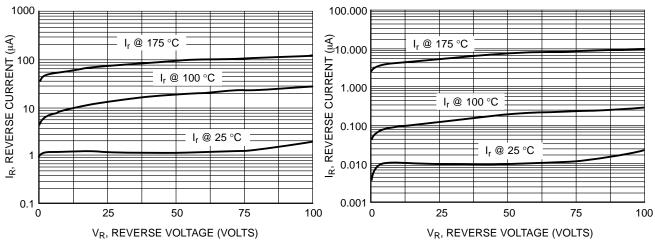


Figure 3. Maximum Reverse Current

Figure 4. Typical Reverse Current

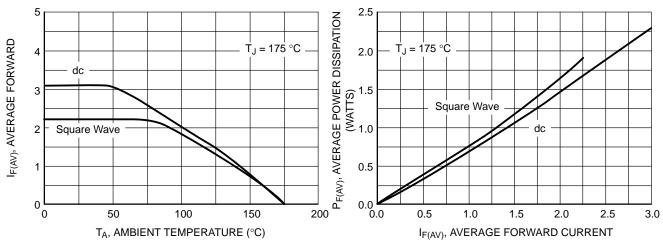


Figure 5. Current Derating

Figure 6. Power Dissipation

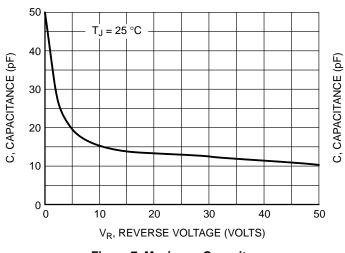


Figure 7. Maximum Capacitance

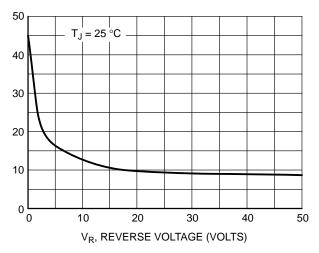


Figure 8. Typical Capacitance

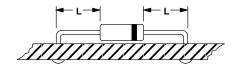
NOTE 4 – AMBIENT MOUNTING DATA

Data shown for thermal resistance junction to ambient $(R_{\theta JA})$ for the mountings shown is to be used as typical guideline values for preliminary engineering or in case the tie point temperature cannot be measured.

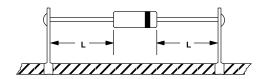
TYPICAL VALUES FOR $R_{\theta \text{JA}}$ IN STILL AIR

Mounti	ng	Lead Length, L			
Method		1/8	1/4	1/2	Units
1		52	65	72	°C/W
2	$R_{\theta JA}$	67	80	87	°C/W
3			50		°C/W

MOUNTING METHOD 1

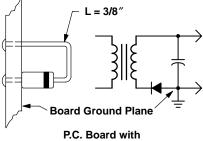


MOUNTING METHOD 2



Vector Pin Mounting

MOUNTING METHOD 3



1–1/2" X 1–1/2" Copper Surface

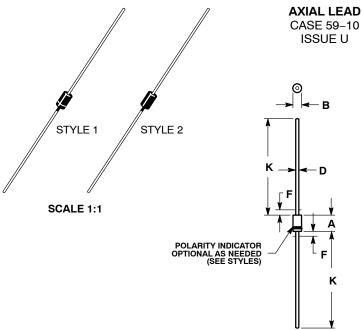
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REVISION HISTORY

Revision	Description of Changes	Date
2	Rebranded the Data Sheet to onsemi format. MUR210, MUR210G, MUR210RL OPN marked as Discontinued.	10/8/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.





STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE

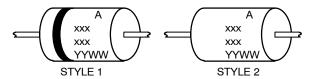
DATE 15 FEB 2005

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

- 2. CONTHOLLING DIMENSION: INCH.
 3. ALL RULES AND NOTES ASSOCIATED WITH JEDEC DO-41 OUTLINE SHALL APPLY
 4. POLARITY DENOTED BY CATHODE BAND.
 5. LEAD DIAMETER NOT CONTROLLED WITHIN F DIMENSION.

ſ		INCHES		MILLIM	ETERS
L	DIM	MIN MAX		MIN	MAX
	Α	0.161	0.205	4.10	5.20
Γ	В	0.079	0.106	2.00	2.70
	D	0.028	0.034	0.71	0.86
	F		0.050		1.27
	K	1.000		25.40	

GENERIC MARKING DIAGRAM*



= Specific Device Code XXX = Assembly Location Α

YY = Year

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

= Work Week WW

NO POLARITY

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